NSN 5961-00-554-1174

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-554-1174 **Inclosure Material:** Ceramic **Overall Length:** 0.565 inches **Overall Diameter:** 1.650 inches **Mounting Method:** Compression **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 1000.0 reverse voltage, peak **Current Rating Per Characteristic:** 400.00 amperes forward current, average **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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